

# HMC-MDB169

## GaAs MMIC FUNDAMENTAL MIXER, 54 - 64 GHz

## **Typical Applications**

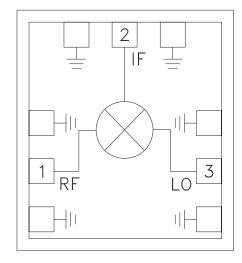
This HMC-MDB169 is ideal for:

- Short Haul / High Capacity Radios
- Point-to-Multi-Point Equipment
- Military Radar, ECM & EW
- SATCOM

#### Features

Passive Double Balanced Topology High LO to RF Isolation: 30 dB Low Conversion Loss: 8 dB Wide IF Bandwidth: DC - 5 GHz Die Size: 0.9 x 1.0 x 0.1 mm

### Functional Diagram



## **General Description**

The HMC-MDB169 is a passive Double Balanced MMIC Mixer which utilizes GaAs Heterojunction Bipolar Transistor (HBT) Shottky diode technology and can be used as either an upconverter or a downconverter. This compact mixer features wide IF bandwidth, low conversion loss and high LO to RF and LO to IF isolation. All bond pads and the die backside are Ti/Au metallized and the Shottky devices are fully passivated for reliable operation. The HMC-MDB169 Double Balanced Mixer is compatible with conventional die attach methods, as well as thermocompression and thermosonic wire bonding, making it ideal for MCM and hybrid microcircuit applications. This compact MMIC is a much smaller and more consistent alternative to hybrid style double balanced mixer assemblies. All data shown herein is measured with the chip in a 50 Ohm environment and contacted with RF probes.

### Electrical Specifications,<sup>[1]</sup> $T_A = 25 \text{ °C}$ , IF = 2 GHz, LO = +13 dBm

Parameter	Min.	Тур.	Max.	Units
Frequency Range, RF & LO	54 - 64			GHz
Frequency Range, IF		DC - 5		GHz
Conversion Loss		8	11	dB
LO to RF Isolation		30		dB
LO to IF Isolation		25		dB
RF to IF Isolation		25		dB
IP3 (Input)		13		dBm
1 dB Compression (Input)		4		dBm

[1] Unless otherwise indicated, all measurements are from probed die

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

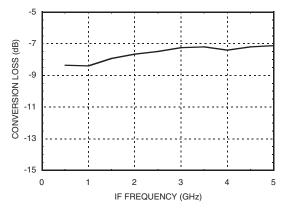
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D



## HMC-MDB169

## GaAs MMIC FUNDAMENTAL MIXER, 54 - 64 GHz

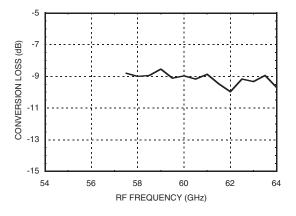
**Upconverter Conversion Loss** 



Note: Measured Performance Characteristics ( $T_{op} = 25^{\circ}C$ )

RF = 59.5 - 64 GHz LO = 59 GHz IF = 0.1 - 5.0 GHz PLO = +13 dBm PRF = -10 dBm

**Downconverter Conversion Loss** 



Note: Measured Performance Characteristics ( $T_{OP} = 25^{\circ}C$ )

RF = 57.5 - 64 GHz LO = 55.5 - 62 GHz IF = 2 GHz PLO = +13 dBm PRF = -5 dBm



## HMC-MDB169

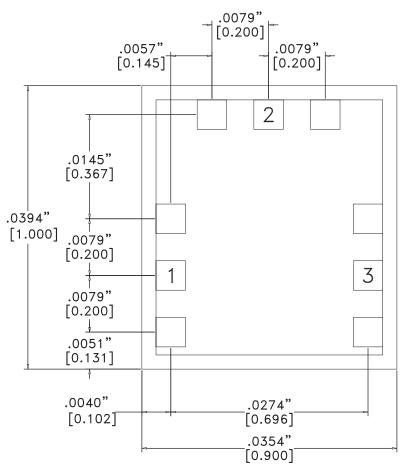
## GaAs MMIC FUNDAMENTAL MIXER, 54 - 64 GHz

### Absolute Maximum Ratings

LO Drive	20 dBm
Storage Temperature	-65 °C to 150 °C
Operating Temperature	-55 °C to 85 °C



## **Outline Drawing**



### Die Packaging Information<sup>[1]</sup>

Standard	Alternate	
GP-2 (Gel Pack)	[2]	

 Refer to the "Packaging Information" section for die packaging dimensions.
For alternate packaging information contact Hittite Microwave Corporation.

#### NOTES:

- 1. ALL DIMENSIONS ARE IN INCHES [MM].
- 2. TYPICAL BOND PAD IS .004" SQUARE.
- 3. BACKSIDE METALLIZATION: GOLD.
- 4. BACKSIDE METAL IS GROUND.
- 5. BOND PAD METALLIZATION: GOLD.
- 6. CONNECTION NOT REQUIRED FOR UNLABELED BOND PADS.
- 7. OVERALL DIE SIZE ±.002"

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D



## HMC-MDB169

## GaAs MMIC FUNDAMENTAL MIXER, 54 - 64 GHz

#### Pad Descriptions

Pad Number	Function	Pin Description	Interface Schematic
1	RF	This pad is DC coupled and matched to 50 Ohms.	RF O
2	IF	This pad is DC coupled.	
3	LO	This pad is DC coupled and matched to 50 Ohms.	

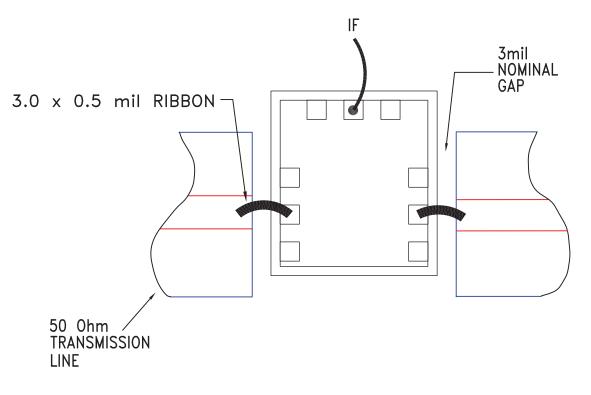


## HMC-MDB169

v01.0209

## GaAs MMIC FUNDAMENTAL MIXER, 54 - 64 GHz





MIXERS - DOUBLE-BALANCED - CHIP



## HMC-MDB169

## GaAs MMIC FUNDAMENTAL MIXER, 54 - 64 GHz

### Mounting & Bonding Techniques for Millimeterwave GaAs MMICs

The die should be attached directly to the ground plane eutectically or with conductive epoxy (see HMC general Handling, Mounting, Bonding Note).

50 Ohm Microstrip transmission lines on 0.127mm (5 mil) thick alumina thin film substrates are recommended for bringing RF to and from the chip (Figure 1). If 0.254mm (10 mil) thick alumina thin film substrates must be used, the die should be raised 0.150mm (6 mils) so that the surface of the die is coplanar with the surface of the substrate. One way to accomplish this is to attach the 0.102mm (4 mil) thick die to a 0.150mm (6 mil) thick molybdenum heat spreader (moly-tab) which is then attached to the ground plane (Figure 2).

Microstrip substrates should be placed as close to the die as possible in order to minimize bond wire length. Typical die-to-substrate spacing is 0.076mm to 0.152 mm (3 to 6 mils).

#### **Handling Precautions**

Follow these precautions to avoid permanent damage.

**Storage:** All bare die are placed in either Waffle or Gel based ESD protective containers, and then sealed in an ESD protective bag for shipment. Once the sealed ESD protective bag has been opened, all die should be stored in a dry nitrogen environment.

**Cleanliness:** Handle the chips in a clean environment. DO NOT attempt to clean the chip using liquid cleaning systems.

Static Sensitivity: Follow ESD precautions to protect against ESD strikes.

**Transients:** Suppress instrument and bias supply transients while bias is applied. Use shielded signal and bias cables to minimize inductive pick-up.

**General Handling:** Handle the chip along the edges with a vacuum collet or with a sharp pair of bent tweezers. The surface of the chip has fragile air bridges and should not be touched with vacuum collet, tweezers, or fingers.

#### Mounting

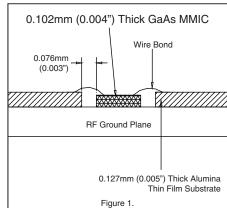
The chip is back-metallized and can be die mounted with AuSn eutectic preforms or with electrically conductive epoxy. The mounting surface should be clean and flat.

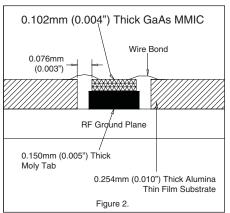
Eutectic Die Attach: A 80/20 gold tin preform is recommended with a work surface temperature of 255 °C and a tool temperature of 265 °C. When hot 90/10 nitrogen/hydrogen gas is applied, tool tip temperature should be 290 °C. DO NOT expose the chip to a temperature greater than 320 °C for more than 20 seconds. No more than 3 seconds of scrubbing should be required for attachment.

Epoxy Die Attach: Apply a minimum amount of epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip once it is placed into position. Cure epoxy per the manufacturer's schedule.

#### Wire Bonding

RF bonds made with 0.003" x 0.0005" ribbon are recommended. These bonds should be thermosonically bonded with a force of 40-60 grams. DC bonds of 0.001" (0.025 mm) diameter, thermosonically bonded, are recommended. Ball bonds should be made with a force of 40-50 grams and wedge bonds at 18-22 grams. All bonds should be made with a nominal stage temperature of 150 °C. A minimum amount of ultrasonic energy should be applied to achieve reliable bonds. All bonds should be as short as possible, less than 12 mils (0.31 mm).





## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF Mixer category:

Click to view products by Analog Devices manufacturer:

Other Similar products are found below :

HMC337-SX HMC404-SX mamx-009646-23dbml HMC339-SX HMC8192-SX MIQ24MS-2 HMC220BMS8GETR M85C HMC554A-SX HMC8192LG HMC521A-SX HMC521ACHIPS CMD258C4 LT5511EFE MAMX-011023-SMB HMC399MS8TR HMC333TR HMC214MS8TR HMC175MS8TR MAMXSS0012TR-3000 109728-HMC129LC4 CSM1-13 SA612AD/01.112 HMC785LP4ETR LT5579IUH#PBF HMC773ALC3BTR HMC558ALC3B HMC329ALC3B MY63H AD8343ARUZ-REEL7 AD608AR AD608ARZ AD831APZ AD831APZ-REEL7 AD8342ACPZ-REEL7 AD8343ARUZ AD8344ACPZ-REEL7 ADL5350ACPZ-R7 ADL5363ACPZ-R7 ADL5365ACPZ-R7 ADL5801ACPZ-R7 ADL5802ACPZ-R7 HMC1056LP4BE HMC1057-SX HMC1063LP3E HMC1093-SX HMC1106-SX HMC129 HMC143 HMC400MS8ETR